

諧振電路



大綱

- □諧振電路的概念與定義
 - ▶阻抗並聯與串聯
 - ➤ 串聯諧振(Series Resonance)
 - ➤ 並聯諧振(Parallel Resonance)
- □電阻轉換



- □所謂諧振電路是指有選擇頻率能力的電路,亦即能使 某頻率的信號源傳送到負載,讓其他頻率的信號衰 減,例如濾波器。
- □ 諧振電路工作的頻寬(Bandwidth)定義為通帶(Passband) 降3dB的頻率範圍。
- □諧振電路的電路Q值定義為

$$Q = \frac{\text{中心頻率}}{3dB$$
頻寬 $= \omega \times \frac{\text{電抗所儲存之能量}}{\text{電阻所消耗之功率}}$



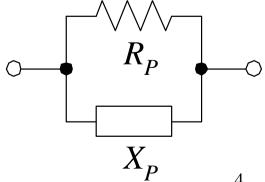
 \square 串聯諧振,等效阻抗為 $Z_S=R_S+jX_S$,若為電感 L_S 電阻 R_S 串聯,則

$$Q_S = \frac{\frac{1}{2}|I|^2 \omega L_S}{\frac{1}{2}|I|^2 R_S} = \frac{\omega L_S}{R_S} = \frac{X_S}{R_S}$$

$$R_S X_S$$

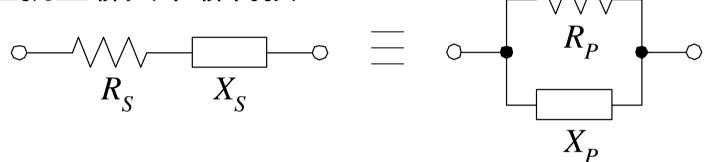
 \square 並聯諧振 , 等效導納為 $Y_p = G_p + jB_p$, 若為電容 C_p 與電 阻 R_p 並聯,則

PH
$$R_P$$
业時,則
$$Q_P = \frac{\frac{1}{2}|V|^2 \omega C_P}{\frac{1}{2}|V|^2 G_P} = \frac{\omega C_P}{G_P} = \frac{B_P}{G_P} = \frac{R_P}{X_P}$$





□阻抗並聯與串聯轉換



在阻抗並聯串聯轉換時,其Q值不變,即

$$Q=Q_S=Q_P=\left(rac{R_P}{R_S}-1
ight)^{rac{1}{2}}$$

其中 $Q_S=rac{X_S}{R_S}=$ 串聯阻抗的 Q 值 $Q_P=rac{R_P}{X_S}=$ 並聯阻抗的 Q 值



□阻抗並聯與串聯轉換(續)

由上述關係可以求得串聯與並聯之轉換公式

$$R_P = (Q_S^2 + 1)R_S, X_P = \frac{R_P}{Q_P}$$

若 $Q_S>>1$,則

$$R_P \approx Q_P^2 R_S$$
, $X_P \approx X_S$

同理,若 $Q_P >> 1$,則

$$R_S \approx \frac{R_P}{Q_P^2}, \qquad X_S \approx X_P$$



串聯諧振

□串聯的RLC諧振電路



ab兩端的等效阻抗為

$$Z_{S} = R_{S} + jX_{L} - jX_{C} = R_{S} + j\omega L - j\frac{1}{\omega C}$$

ightharpoonup 在共振頻率 $\omega=\omega_r$ 時,電抗部份等於零,使 Z_S 等於一純電阻 R_S ,稱為串聯諧振, $\omega_r=2\pi f_r$ 為串聯諧振的共振頻率,即

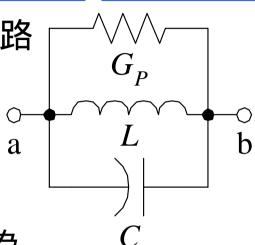
$$\omega_r L - \frac{1}{\omega_r C} = 0 \Rightarrow \omega_r = \frac{1}{\sqrt{LC}}$$

$$\omega = \omega_r$$
 時, Z_S 值為最小。



並聯諧振

□並聯的RLC諧振電路



ab兩端的等效導納為

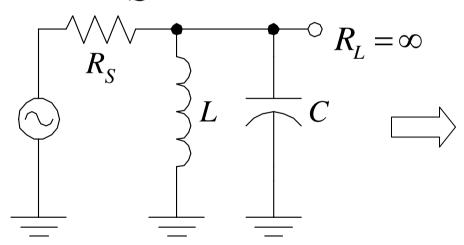
$$Y_P = G_P - jB_L + jB_C = G_P - j\frac{1}{\omega L} + j\omega C$$

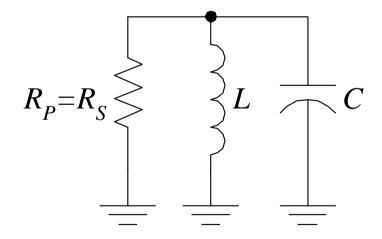
ightharpoonup 在共振頻率 $\omega=\omega_r$ 時,電納部份等於零,稱為並聯諧振,即 $-\frac{1}{\omega_rL}+\omega_rC=0\Rightarrow\omega_r=\frac{1}{\sqrt{LC}}$

 $\omega = \omega_r$ 時, Y_P 值為最小或等效阻抗 Z_P 為最大。 Microwave & Communication Lab.



- 口諧振電路的Q值定義為中心頻率與3dB頻寬的比,通常稱之為負載Q值(Loaded Q);若諧振電路負載 R_L = 時的電路Q值則稱為無載Q值(Unloaded Q)。
 - ▶無載 ②値

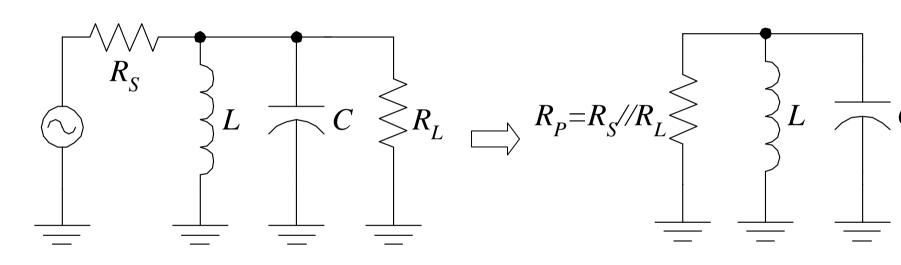




$$Q_U = \frac{R_P}{X_P} = \frac{R_P}{X_L} = \frac{R_P}{X_C}$$



➤負載Q值

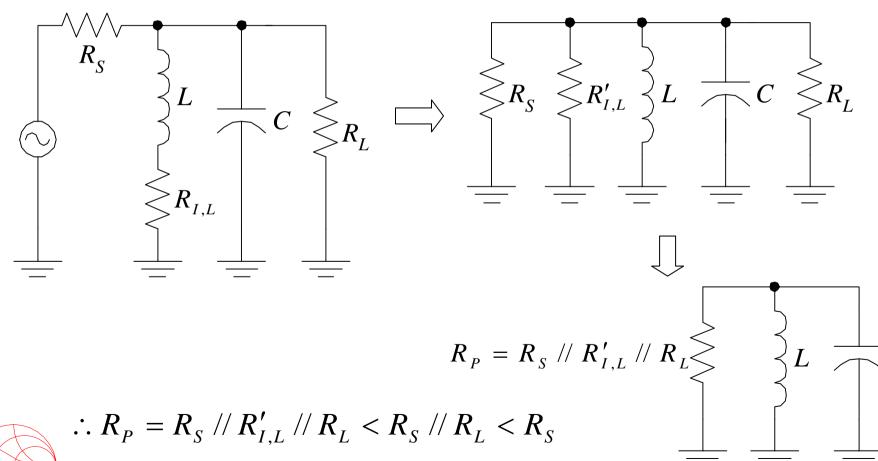


$$Q_L = \frac{R_P}{X_P} = \frac{R_P}{X_L} = \frac{R_P}{X_C}$$

$$R_P = \frac{R_S}{R_L} < R_S \Rightarrow Q_U > Q_L$$



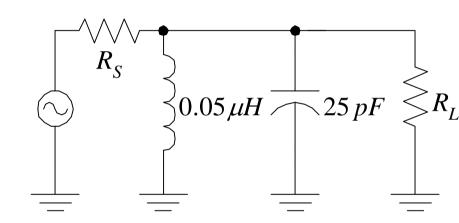
➤ Poor Component (Lossy)





□例題1

- (1)試求中心頻率。
- (2)當 R_S = 50Ω 及 R_S = $1K\Omega$ 時,試求無載Q值。
- (3)當 $R_S = R_L = 1K\Omega$ 時,並且 $Q_r = Q_C = \infty$,試求負載Q值。
- (4)若 R_S = R_L = $1K\Omega$,並且 Q_I =10, Q_C = ∞ ,試求負載Q值。





$$f_r = \frac{1}{2\pi\sqrt{LC}} = \frac{1}{2\pi\sqrt{(0.05\times10^{-6})(25\times10^{-12})}} = 142.4(MHz)$$

(2)
$$Q_{U,50} = \frac{R_P}{X_P} \Big|_{f=f_r} = \frac{50}{\omega_r L} = 1.1$$

$$Q_{U,1K} = \frac{R_P}{X_P} \Big|_{f=f_r} = \frac{1K}{\omega_r L} = 22.4$$

(3)
$$Q_{L,1K} = \frac{R_P}{X_P} \bigg|_{f=f} = \frac{R_S // R_L}{\omega_r L} = \frac{500}{\omega_r L} = 11.2$$



$$Q_I = \frac{X_L}{R_{I,L}} \Rightarrow R_{I,L} = \frac{X_L}{Q_I} = 4.55$$

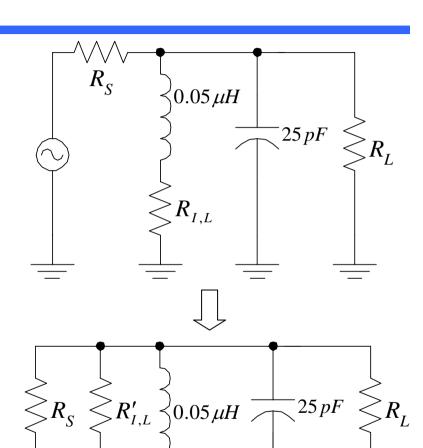
$$R'_{I,L} \approx Q_I^2 R_{I,L} = 455\Omega$$

$$\Rightarrow X_L' = \frac{R_{I,L}'}{Q_I} = 45.5\Omega$$

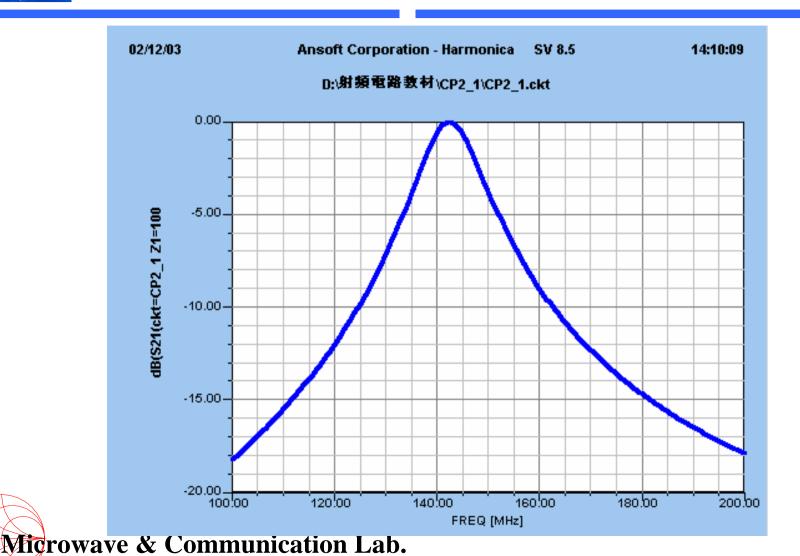
$$R_P = R_S // R'_{I,L} // R_L$$

$$=1K//455/1K=237.4\Omega$$

$$\therefore Q_L = \frac{R_P}{X_L'} = 5.3$$

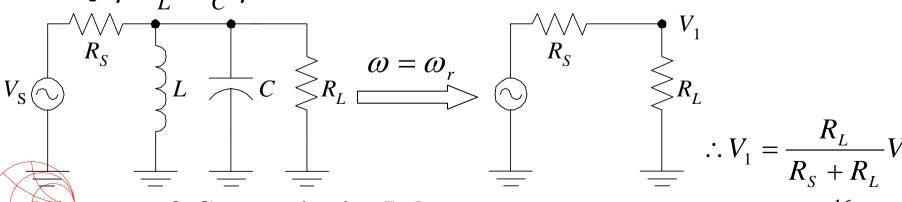






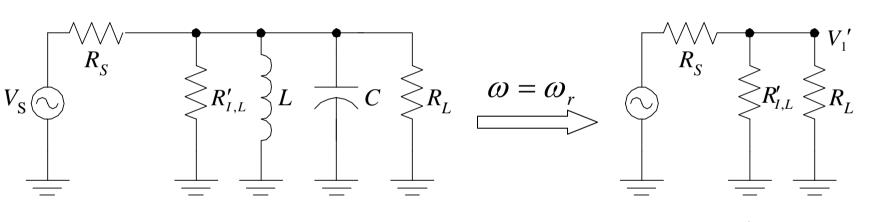


- 口若欲提高負載Q值 Q_L ,即提升電路的選擇性,可以增加 R_P 或減少 X_P ,所以在設計較佳選擇性的諧振電路時,通常選取:
 - \triangleright 較大值得信號源內阻 R_s 及負載阻抗 R_L 。
 - ▶低值的電感並配合高值的電容器。
- 口電路中電感L及電容C為理想元件,當達共振頻率 ω_r 時, $X_L = X_C$,





 \Box 但若電感L為非理想元件,當達到共振頻率 ω_r 時, $X_r' = X_c$



$$\therefore V_1' = \frac{R_{I,L}'/R_L}{R_S + (R_{I,L}'/R_L)} V_S$$

則插入損耗
$$IL = 20 \log \left(\frac{V_1'}{V_1} \right)$$



□例題2

一LC並聯電路其3dB頻寬為 $10MH_Z$,中心頻率為 $100MH_Z$, $R_S=R_L=1K\Omega$, $Q_r=85$, $Q_C=\infty$,試求插入損耗。

[解]

$$Q_{L} = \frac{f_{0}}{BW} = \frac{100MHz}{10MHz} = 10$$

$$Q_{L} = \frac{R_{P}}{X_{L}} = \frac{R_{S} // R'_{I,L} // R_{L}}{X_{L}} = 10$$

$$Q_{I} = \frac{R'_{I,L}}{X_{I}} = 85$$

$$\therefore Q_L = \frac{500/85X_L}{X_L} = 10 \Rightarrow X_L = 44.1\Omega$$



若無損耗之電路
$$Q_I = Q_C = \infty$$

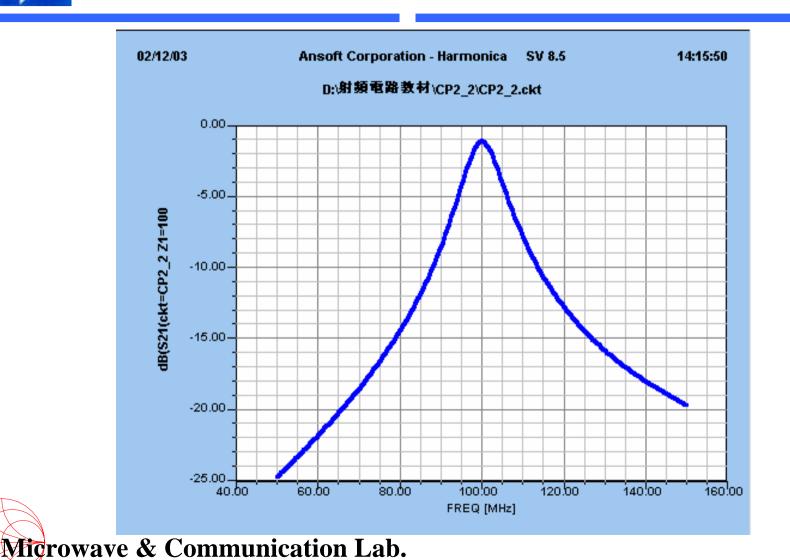
$$V_1 = \frac{R_L}{R_S + R_L} V_S = 0.5 V_S$$

實際之電路
$$Q_I = 85$$
 & $Q_C = \infty$

$$V_1' = \frac{R_{I,L}'/R_L}{R_S + (R_{LL}'/R_L)} V_S = 0.44 V_S$$

$$\Rightarrow IL = 20\log\left(\frac{V_1'}{V_1}\right) = 20\log\left(\frac{0.44V_S}{0.5V_S}\right) = -1.1 \quad dB$$



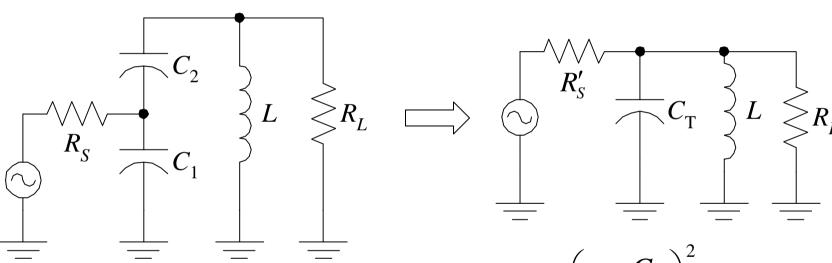




- □阻抗轉換的目的:
 - ightharpoonup 諧振電路之負載Q值 Q_L 決定電路之頻寬,影響對頻率之選擇性。
 - ▶低信號源阻抗或低負載阻抗會降低電路之負載Q值。
 - ➤經由電阻轉換將阻抗提高以達到高負載Q值、窄頻寬之要求。
- □常用阻抗轉換轉換的方法有:
 - ➤電容抽頭(Tapped-C)諧振電路
 - ➤電感抽頭(Tapped-L)諧振電路



□電容抽頭諧振電路

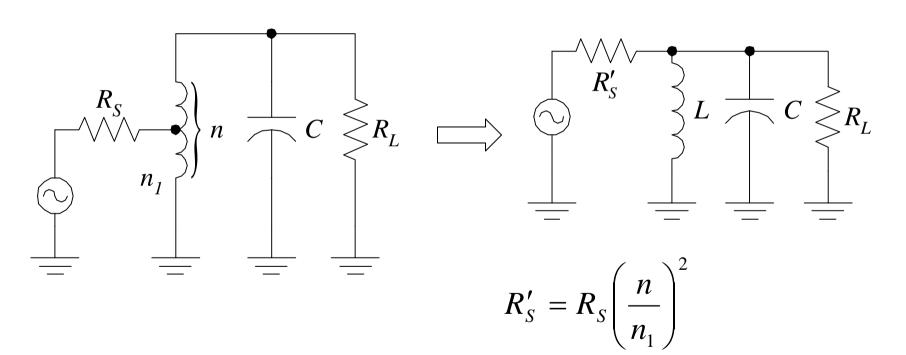


$$R_S' = R_S \left(1 + \frac{C_1}{C_2} \right)$$

$$C_T = \frac{C_1 C_2}{C_1 + C_2}$$



□電感抽頭諧振電路



 $\therefore L \propto n \Rightarrow \left(\frac{R_S'}{R_S}\right)^{\frac{1}{2}} = \frac{L}{L_1}$



□例題3

設計一諧振電路 Q_L =20,中心頻率為 $100MH_Z$, R_S =50 Ω , R_L = $2K\Omega$,且 Q_I = Q_c = ∞ 。

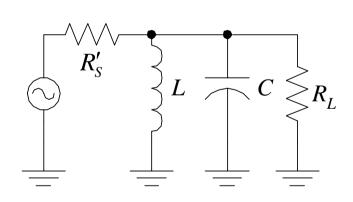
 $[\mathbf{M}]$ 為了使有最大功率傳輸 $\Rightarrow R'_S = R_L = 2K\Omega$

$$Q_{L} = \frac{R'_{S} // R_{L}}{X_{P}} = 20$$

$$\Rightarrow \frac{1K}{X_{P}} = 20 :: X_{P} = 50$$

$$X_{L} = \omega L = 50 \Rightarrow L = 79.5nH$$

$$X_{C} = \frac{1}{\omega C} = 50 \Rightarrow C = 31.8pF$$

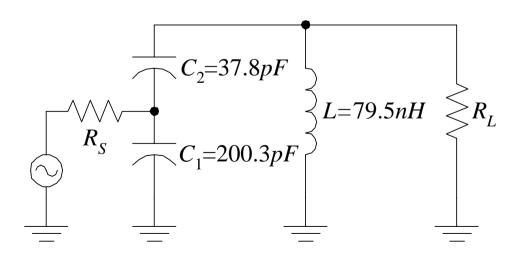




[解](續)電容抽頭阻抗轉換

$$\frac{C_1}{C_2} = \sqrt{\frac{R_S'}{R_S}} - 1 = 5.3 \Rightarrow C_1 = 5.3C_2$$

$$C = \frac{C_1 C_2}{C_1 + C_2} = 31.8 pF \Rightarrow C_1 = 200.3 pF, \quad C_2 = 37.8 pF$$





[解](續)電感抽頭阻抗轉換

$$\left(\frac{R_S'}{R_S}\right)^{\frac{1}{2}} = \frac{L}{L_1} \Rightarrow (40)^{\frac{1}{2}} = \frac{L}{L_1} \Rightarrow L = 6.32L_1 = 79.6nH \Rightarrow L_1 = 12.6nH$$

$$\Rightarrow L = L_1 + L_2 = 79.6nH \Rightarrow L_2 = 67nH$$

